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	<i>This document specifies that referenced product(s) is(are) compliant to</i> PGQ 15: GENERAL PRINCIPLES OF QUALIFICATION	

PRODUCT DESCRIPTION	E2V PART-NUMBER	PACKAGE	Temp. range	Screening level
12-bit 3Gsps MuxDAC	EV12DS130BMLG9NB1	CLGA 255	-55°C < Tc Tj < 125°C	ESCC 9000
	EV12DS130BMGS9NB1	CI-CGA 255		
	EV12DS130BMGC9NB1	CCGA 255		

QUALIFICATION STATUS	<input checked="" type="checkbox"/> ACCEPTED	<input type="checkbox"/> PENDING	<input type="checkbox"/> REJECTED
<i>Products listed above have met all requirements of PGQ15</i>			

DICE INFORMATION	Wafer fab	INFINEON - Regensburg (Germany)
	Process	B7HF200
	Technology	200Ghz SiGe Bipolar
	Mask	VN54B
	Die size	5.04 mm x 4.67 mm (23.54 mm ²)
	Die thickness	300 µm
	Passivation	SiO2 (0.3 µm) & SiN (0.55 µm)
	Last metallization layer	Au (500nm) / Pt (60nm) / Ti (60nm)
PACKAGE INFORMATION	Outline	21 x 21 mm
	Pitch	1.27 mm
	Die attach material	JM7000
	Wire	Au 23 µm
	Lid	COMBO HIREL OD .645SQ
	Marking ink	Markem 4489 black
	LG	CLGA 255 - Au pad termination
	GS	CI-CGA 255 - Solder column interposer Pb 90 / Sn 10
	GC	CCGA 255 - Cu spiral column Pb 80 / Sn 20
ASSEMBLY LOCATION	e2v semiconductors - St Egrève - France	
TEST LOCATION		

Authorized Signature	Validation Date (Last update)
Christian CARMONA Semiconductors Quality Officer & DLA point of contact 	February 19th 2016

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QUALIFICATION BATCH INFORMATION					
Mask VN54B	Diffusion lot RU349519	Assy lot ID / WO 99000041 / 990000833	Date Code 1433		
TEST	METHODE	COND	DESCRIPTION	Qualif. sample	Σ (1)
Construction analysis	MIL-STD-883 TM2018 ESA/SCC N°21400		8 dice from RU349519 diff lot	Pass	All diffusion lot
ESD HBM	JESD22-A114E	>1000V	Class 1C	5(0)	-
LATCH UP	JEDEC 78B		Class I Class II	6(0) 6(0)	- -
HTOL Test	MIL-STD-883 TM1005		4000Hrs / Tj 156°C	22(0)	-
Reflow simulation	J-STD-020D	3x	SnPb profil peak >220°C	0	12(0)
Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.			
Interm. electrical	Device specification				
Reflow simulation	J-STD-020D	2x	SnPb profil peak >220°C		
Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.			
Interm. & End-point elect.	Device specification				
Temperature cycling	MIL STD 883 TM1010	C.	100cy	0	12(0)
Thermal shock	MIL STD 883 TM1011	C. 100cy	-65°C/2min then +150°C/2min		
Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.			
Temp. cycling	MIL STD 883 TM1010	C.	400cy		
Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.			
External visual inspection	ESCC 20500				
End-point elect.	Device specification				
DPA	Internal inspection		wire loops & pad intermetallic		
Mechanical Shock	MIL STD 883 TM 2002	B. 5x	5x6 axis: duration of pulse 0.5ms/1500g		
Vibration	MIL STD 883 TM 2007	A. 12x	3 axis: 20-2000 Htz/20G/4min		
Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.			
External visual inspection	ESCC 20500				
Intermediate-point elect.	Device specification				
Mechanical Shock	MIL STD 883 TM 2002	B. 45x	5x6 axis: duration of pulse 0.5ms/1500g		
Vibration	MIL STD 883 TM 2007	A. 108x	3 axis: 20-2000 Htz/20G/4min		
Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.			
External visual inspection	ESCC 20500				
End-point elect.	Device specification				

⁽¹⁾ Σ corresponds to cumulative tests done on same package family

Reliability information:				
<i>Note: This mask set does not have yet enough cumulated component hours to calculate a reliable MTTF. However, cumulative LFR data of the product family allow for a more significant MTTF.</i>				
RELIABILITY REPORT <i>Cumulative EFR & LFR</i>	Equivalent Tj Tj 125°C	Nb components hours 2970579	Nb failure 0	Activation Energy 0.7 eV
e2v Calculation	For Tj 125°C	Confidence level: 60 %	LFR = 309 FIT	MTTF = 3 241 221 Hrs (370 Years)
Extrapolation with ARRHENIUS law	For Tj 110°C	Confidence level: 60 %	LFR = 139 FIT	MTTF = 7 200 299 Hrs (822 Years)
	For Tj 90°C	Confidence level: 60 %	LFR = 43 FIT	MTTF = 23 126 148 Hrs (2640 Years)

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PRODUCT FAMILY INFORMATION (for cumulative calculation)							
Mask		Product		Description		Package	
VN15A		EV10DS130A		10bit 3Gsps MuxDAC		CLGA255 / CI-CGA255 / CCGA255	
VN15A		EV12DS130A		12bit 3Gsps MuxDAC		CLGA255 / CI-CGA255 / CCGA255	
VN54B		EV12DS130B		12bit 3Gsps MuxDAC		CLGA255 / CI-CGA255 / CCGA255	
VN41A		EV10AS180A		10bit 1.5Gsps ADC		CLGA255 / CI-CGA255 / CCGA255	
LAT Sub.	TEST	METHODE	COND	DESCRIPTION		LAT-QCI sample ⁽¹⁾	Σ ⁽²⁾
LAT3 B1	Resistance to solvents	MIL-STD-883 TM2015				0	9(0)
	Permanence of marking	ESCC 24800				0	20(0)
LAT3 B2	Internal visual inspection	MIL-STD-883 TM2010				0	19(0)
	Bond strength	MIL-STD-883 TM2011		22 bonds x 4 devices		0	360(0)
	Bond shear	ASTM-F1269-06		10 bonds x 4 devices		0	360(0)
	Substrate attach strength	MIL-STD-883 TM2027				0	18(0)
LAT3 B3	Solderability	MIL-STD-883 TM2003				0	7(0)
		JESD22-B102E				0	9(0)
LAT3 B4	Solder column pull test	MIL-STD-883 TM2038		45 columns from 2 parts		0	144(0)
LAT2 C	HTOL Test	MIL-STD-883 TM1005		4000Hrs / Tj 156°C		22(0)	37(0)
				2000Hrs / 156°C		22(0)	217(0)
				500Hrs / Tj 156°C		22(0)	67(0)
	Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.			100%(0)	100%(0)
External visual inspection	MIL-STD-883 TM2009						
Interm. & End-point elect.	Device specification						
D1	Physical dimensions	MIL-STD-883 TM2016		Included in screening		100%(0)	100%(0)
LAT1 D3	Thermal shock	MIL-STD-883 TM1011	C. 15cy			0	128(0)
	Temperature cycling	MIL-STD-883 TM1010	C. 100cy				
	Moisture resistance	MIL-STD-883 TM1004					
	Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.				
	External visual inspection	MIL-STD-883 TM2009					
	End-point electrical	Device specification					
LAT1 D4	Mechanical shock	MIL-STD-883 TM2002	B.			0	128(0)
	Vibration	MIL-STD-883 TM2007	A.				
	Constant acceleration	MIL-STD-883 TM2001	D. Y1				
	Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.				
	External visual inspection	MIL-STD-883 TM2009					
	End-point electrical	Device specification					
D5	Salt atmosphere	MIL-STD-883 TM1009	A.			0	15(0)
	External visual inspection	MIL-STD-883 TM2009					
	Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.				
D6	Internal water vapor test	MIL-STD-883 TM1018		Monitoring		0	-
D9	Soldering heat	MIL-STD-883 TM2036				0	3(0)
	Seal (fine & gross leaks)	MIL-STD-883 TM1014	A. & C.				
	External visual inspection	MIL-STD-883 TM2009					
	End-point electrical	Device specification					

⁽¹⁾ LAT & QCI tests done on EV12DS130B devices

⁽²⁾ cumulative LAT & QCI tests done on same product family